National Semiconductor

MICROCIRCUIT DATA SHEET

MDLM137HV-H REV 1A1

Original Creation Date: 07/12/95
Last Update Date: 04/16/99
Last Major Revision Date: 04/02/99

ADJUSTABLE, 3-TERMINAL NEGATIVE VOLTAGE REGULATOR (HIGH VOLTAGE)

General Description

The LM137HVH is an adjustable 3-terminal negative voltage regulator capable of supplying in excess of -0.5A over an output voltage range of -1.2V to -47V. This regulator is exceptionally easy to apply, requiring only 2 external resistors to set the output voltage and 1 output capacitor for frequency compensation. The circuit design has been optimized for excellent regulation and low thermal transients. Further, the LM137HVH features internal current limiting, thermal shutdown and safe-area compensation, making it virtually blowout-proof against overloads.

The LM137HVH serves a wide variety of applications including local on-card regulation, programmable-output voltage regulation or precision current regulation. The LM137HVH is an ideal complement to the LM117HVH adjustable positive regulator.

Industry Part Number

LM137HV

NS Part Numbers

LM137HVH-QMLV
LM137HVH-SMD

Prime Die

LM137HV

Controlling Document

SEE FEATURES SECTION

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp (^{O}C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- Output voltage adjustable from -1.2V to -47V.
- 0.5A output current guaranteed, -55 C to +150 C.
- Line regulation typically 0.01%/V.
- Load regulation typically 0.3%.
- Excellent thermal regulation, 0.002%/W.
- 77 dB ripple rejection.
- Excellent rejection of thermal transients.
- 50 ppm/ C temperature coefficient.
- Temperature-independent current limit.
- Internal thermal overload protection.
- Standard 3-lead transistor package.
- Output short circuit protected.
- CONTROLLING DOCUMENT

LM137HVH-SMD	5962-7703404XA
LM137HVH-QMLV	5962-7703404VXA

(Absolute Maximum Ratings)
(Note 1)

Power Dissipation (Note 2)	Internally Limited
Input-Output Voltage Differential	50V
Operating Ambient Temperature Range	-55 C to +125 C
Maximum Junction Temperature (Note 2)	150 C
Storage Temperature Range	-65 C to +150 C
Lead Temperature (Soldering, 10 seconds)	300 C
Thermal Resistance	
ThetaJA (Still Air)	174 C/W
ThetaJA (500LF/Min Air Flow)	64 C/W
ThetaJC	15 C/W
Package Weight (Typical)	955mg
ESD Rating (Note 3)	4000V

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by Tjmax (maximum junction temperature), ThetaJA (package junction to ambient thermal resistance), and TA (ambient temperature). The maximum allowable power dissipation at any temperature is Pdmax = (Tjmax - TA)/ThetaJA or the number given in the Absolute Maximum Ratings, whichever is lower.

Note 3: Human body model, 100pF discharged through 1.5K Ohms

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
DC: Il = 8mA

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vref	Reference Voltage	Vdiff = 3V			-1.275	-1.225	V	1
					-1.3	-1.2	V	2, 3
		Vdiff = 40V			-1.275	-1.225	V	1
					-1.3	-1.2	V	2, 3
		Vdiff = 50V			-1.275	-1.225	V	1
					-1.3	-1.2	V	2, 3
Rline	Line Regulation	-50V ≤ Vdiff ≤ -3V			-10	10	mV	1
					-25	25	mV	2, 3
Rload	Load Regulation	Vdiff = 50V, 8mA ≤ Iout ≤ 100mA			-25	25	mV	1
		Vdiff = 5V, 8mA ≤ Iout ≤ 500mA			-31	31	mV	1
					-50	50	mV	2, 3
Vrth	Thermal Regulation	Vin = -16.5V, Il = 330mA, Pd = 5 Watts, t = 10mS			-2.0	2.0	mV	1
Iadj	Adjustment Pin Current	Vdiff = 3V				100	uA	1, 2, 3
		Vdiff = 40V				100	uA	1, 2, 3
		Vdiff = 50V				100	uA	1, 2, 3
Delta Iadj(load)	Adjustment Pin Current Change	Vdiff = 5V, 8mA ≤ Iout ≤ 200mA			-5	5	uA	1, 2, 3
Delta Iadj(line)	Adjustment Pin Current Change	Il = 8mA, -50V ≤ Vdiff ≤ -3V			-6	6	uA	1, 2, 3
Ilmin	Minimum Load Current	Vdiff = 3V, Vout = -1.4V (forced)				3	mA	1, 2, 3
		Vdiff = 10V, Vout = -1.4V (forced)				3	mA	1, 2, 3
		Vdiff = 40V, Vout = -1.4V (forced)				5	mA	1, 2, 3
		Vdiff = 50V, Vout = -1.4V (forced)				5	mA	1, 2, 3
Icl	Current Limit	Vdiff = 5V			0.5	1.8	A	1, 2, 3
		Vdiff = 50V			0.1	0.65	A	1

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
AC: Il = 8mA

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Rn	Ripple Rejection	f = 120Hz, Vout = Vref, Cadj = 10uF	1, 2		66		dB	4, 5, 6

DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.)
DC: "Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 only"

Rline	Line Regulation	-50V ≤ Vdiff ≤ -3V			-4.0	+4.0	mV	1
Vref	Reference Voltage	Vdiff = 3.0V			-0.01	+0.01	V	1
		Vdiff = 40V			-0.01	+0.01	V	1
		Vdiff = 50V			-0.01	+0.01	V	1
Iadj	Adjustment Pin Current	Vdiff = 3.0V			-10	+10	uA	1
		Vdiff = 40V			-10	+10	uA	1
		Vdiff = 50V			-10	+10	uA	1

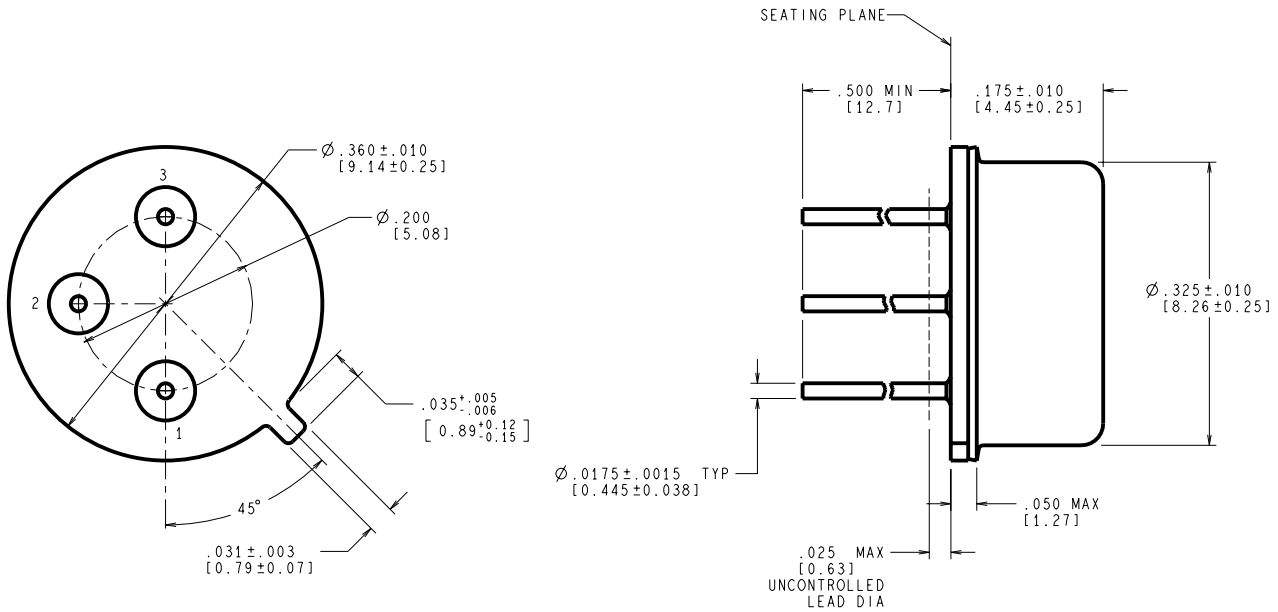
Note 1: Group "A" sample only, test at all temperature.
Note 2: Bench test per RPI-3-362. Use TDN 70256657(NSSG).

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
05192HRB2	METAL CAN (H), TO-39, 3LD, .200 DIA P.C. (P/P DWG)
H03ARD	METAL CAN (H), TO-39, 3LD, .200 DIA P.C. (P/P DWG)
P000199A	METAL CAN (H), TO-39, 3 LEAD (PINOUT)

See attached graphics following this page.

REVISIONS				
LTR	DESCRIPTION	E.C.N.	DATE	BY/APP'D
C	REVISE & REDRAW PER NEW STANDARD	10403	05/24/94	TL/GM
D	UPDATE MILAERO STAMP; Ø.325 WAS Ø.326; REVISE TOLERANCES	10798	02/28/95	TL/



CONTROLLING DIMENSION IS INCH
VALUES IN [ ] ARE MILLIMETERS

NOTES: UNLESS OTHERWISE SPECIFIED

1. LEADS TO BE LOCATED WITHIN .010 IN/ 0.25 mm OF THEIR TRUE POSITIONS RELATIVE TO A MAXIMUM WIDTH TAB.
2. STANDARD METAL CAN TYPE: SOLID BASE, KOVAR.
3. APPLIES TO MIL-AERO AND LINEAR PRODUCTS.
4. REFERENCE JEDEC REGISTRATION TO-39, JEDEC PUBLICATION No. 95.

MIL-I-38535
CONFIGURATION CONTROL

APPROVALS	DATE
DRAWN T. LEQUANG	05/24/94
DFTG. CHK.	
ENGR. CHK.	

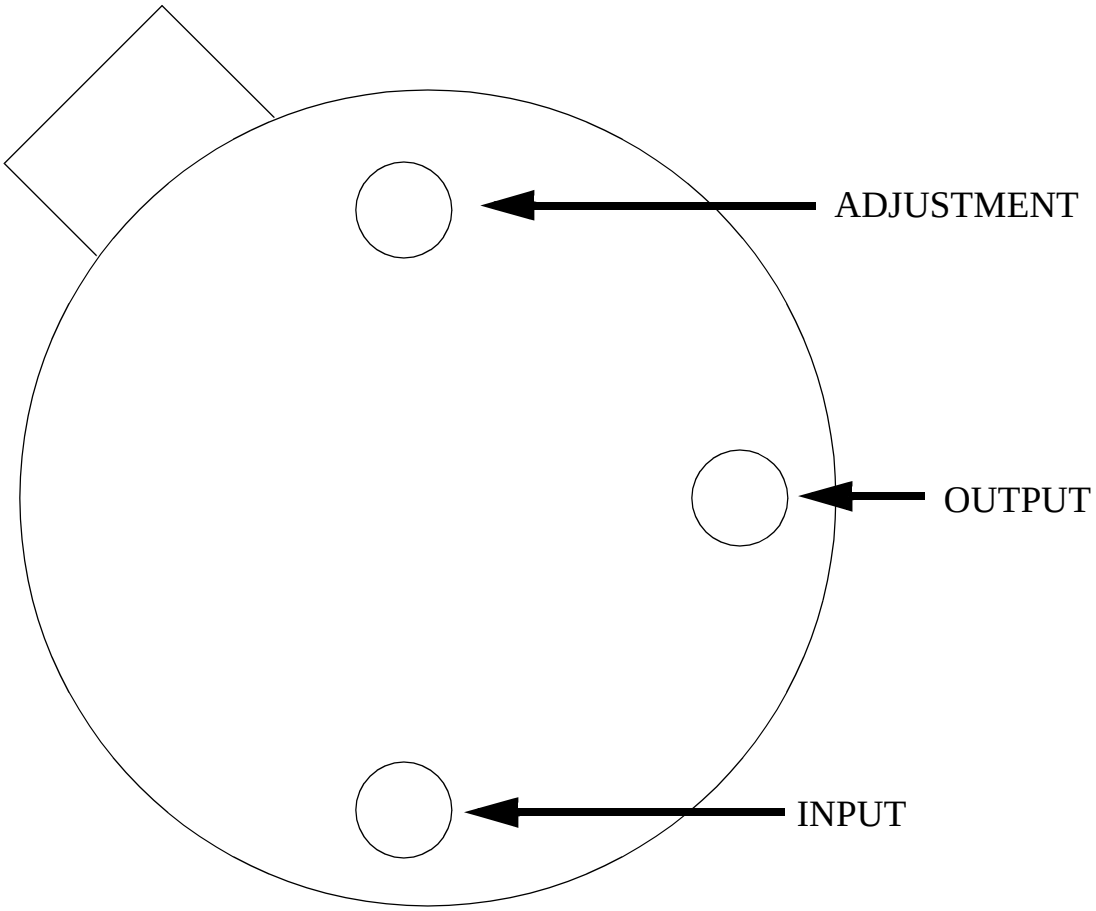
National Semiconductor
2900 Semiconductor dr, Santa Clara, CA 95052-8090

METAL CAN, TO-39, 3 LEAD, .200 DIA P.C.

PROJECTION
INCH [MM]

SCALE	SIZE	DRAWING NUMBER	REV
N/A	C	MKT-H03A	D

DO NOT SCALE DRAWING | SHEET 1 of 1



LM137H, LM137HVH
3 - LEAD TO-39
CONNECTION DIAGRAM
BOTTOM VIEW
P000199A

National Semiconductor™
MIL/AEROSPACE OPERATIONS
2900 SEMICONDUCTOR DRIVE
SANTA CLARA, CA 95050

Revision History

Rev	ECN #	Rel Date	Originator	Changes
1A1	M0003375	04/16/99	Rose Malone	Update MDS: MDLM137HV-H, Rev. 0A0 to MDLM137HV-H, Rev. 1A1. Added reference to QMLV device to Main Table, ESD Limit and Thermal Resistance, Package weight to Absolute Maximum Section and Drift Table to Electrical section.